

L Number	Hits	Search Text	DB	Time stamp
1	3	((374/178).CCLS.) AND @pd>20030801	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 10:46
2	9	((374/183).CCLS.) AND @pd>20030801	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 10:46
8	0	(second or pair) adj semiconductor and 374/\$.ccls. and current adj source and @pd>20030801	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 10:49
9	1	(second or pair) adj semiconductor and 374/\$.ccls. and @pd>20030801	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 10:50
11	0	voltage same divid\$3 with plurality adj (factors or constants or ratios) and 374/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 10:50
7	23	bipolar adj transistor and darlington and @pd>20030801	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 10:51
13	3	semiconductor with temperature and current and ratio with voltage same converter and @pd>20030801	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 10:52
12	8	semiconductor with temperature and current and divid\$3 with voltage same converter and @pd>20030801	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 10:52
10	8	(bipolar adj transistor and darlington) and temperature and @pd>20030801	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/12/05 10:52